

series Low Power Voltage Detector

Features

- Low power consumption
- Low temperature coefficient
- Built-in hysteresis characteristic

Applications

- Battery checkers
- Level selectors
- Power failure detectors

- Output voltage accuracy: tolerance \pm 1% or \pm 2%
- TO92, SOT89 and SOT23 package

High input voltage (up to 12V)

- Microcomputer reset
- Battery memory backup
- Non-volatile RAM signal storage protectors

General Description

The Misseries devices area set of three terminal low power voltage detectors implemented in CMOS technology. Each voltage detector in the series detects a particular fixed voltage ranging from 0.9V to 5.0V. The voltage detectors consist of a high-precision and low power consumption standard voltage source as well as a comparator,

hysteresis circuit, and an output driver (CMOS inverter or NMOS open drain). CMOS technology ensures low power consumption.

Although designed primarily as fixed voltage detectors, these devices can be used with external components to detect user specified threshold voltages.

Selection Table

Part No.	Det. Voltage	Hys. Width	Output	Tolerance	Package
HM61C092XX	0.9V	4%	CMOS	<u>+2</u> %	
HM61N092XX	0.9V	4%	NMOS	<u>+2</u> %	
HM61C102XX	1.0V	4%	CMOS	<u>+2</u> %	
HM61N102XX	1.0V	4%	NMOS	<u>+2</u> %	T002
HM61C112XX	1.1V	4%	CMOS	<u>+2</u> %	TO92 SOT89
HM61N112XX	1.1V	4%	NMOS	<u>+2</u> %	SOT23-3
HM61C122XX	1.2V	4%	CMOS	±2%	SOT23-5 SOT23-5
HM61N122XX	1.2V	4%	NMOS	<u>+2</u> %	30123-3
•••	•••	4%	•••	±2%	
HM61C502XX	5.0V	4%	CMOS	±2%	
HM61N502XX	5.0V	4%	NMOS	±2%	

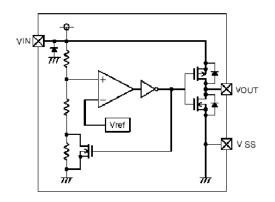
Order Information

HM61(1)(2)(3)(4)(5)(6)(7)

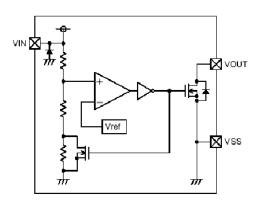
DESIGNATOR	DESCRIPTION	DESIGNATOR	DESCRIPTION
	Output Configuration:		Package Type:
1)	C=CMOS		M=SOT23-3
	N=N-ch open drain	6	P=SOT89
	Data et Valta es	0	N=SOT25
00	Detect Voltage		T=TO-92(Standard)
23	25=2.5V		L=TO-92(Custom pin configuration
	38=3.8V		Device Orientation:
(4)	Output Delay		R=Embossed Taped(Right)
4	0=No delay	7	L=Embossed Taped(Left)
(E)	Detect Accuracy:		H=Paper Type(TO-92)
5	$2=$ with $\pm 2\%$		B=Bag(TO-92)

Block Diagram

(1) CMOS Output

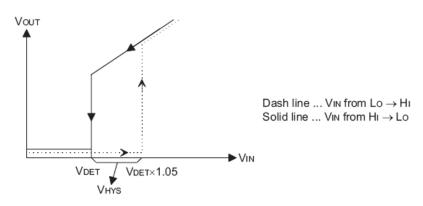


(2) N-ch Open Drain Output

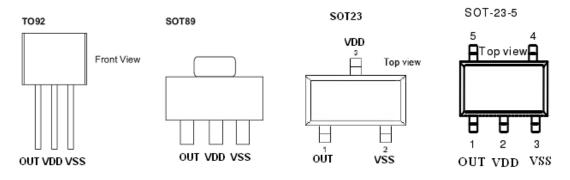


Output Table & Curve

Ī	V_{DD}	$V_{DD}>V_{DET}(+)$	V _{DD} ≪V _{DET} (-)
	V_{OUT}	Hi-Z	V _{SS}



Pin Assignment

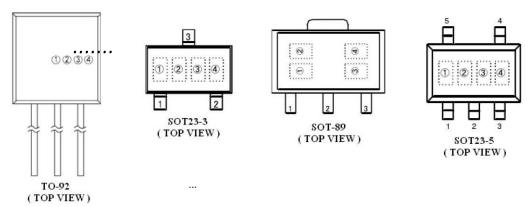


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"=U series Low Power Voltage Detector"

Marking Rule



①Represents the output configuration

Symbol	Product Description
С	HM61 ◆◆◆◆◆◆ "

2Represents the Output configuration and detect voltage range

DESIGNATOR	OUTPUT CONFIGURATION	VOLTAGE RANGE (V)
A	CMOS	0.1~3.0
В	CMOS	3.1~6.0
N	OPEN DRAIN	0.1~3.0
Р	OPEN DRAIN	3.1~6.0

③Represents the detect voltage

DESIGNATOR	DE	ETECT VOL	TAGE (V)	DESIGNATIOR	DE'	TECT VOI	LTAGE (V	<i>I</i>)
0	-	3. 1	-	3. 15	F	1.6	4.6	1.65	4. 65
1	_	3. 2	_	3. 25	Н	1.7	4. 7	1.75	4. 75
2	-	3. 3	-	3. 35	K	1.8	4.8	1.85	4.85
3	-	3. 4	-	3. 45	L	1.9	4. 9	1.95	4. 95
4	-	3. 5	-	3. 55	M	2.0	5. 0	2.05	5. 05
5	_	3. 6	_	3. 65	N	2. 1	5. 1	2. 15	5. 15
6	-	3. 7	-	3. 75	P	2.2	5. 2	2. 25	5. 25
7	-	3.8	-	3. 85	R	2.3	5. 3	2.35	5. 35
8	0.9	3. 9	-	3. 95	S	2.4	5. 4	2.45	5. 45
9	1.0	4. 0	-	4. 05	T	2.5	5. 5	2.55	5. 55
A	1. 1	4. 1	_	4. 15	U	2.6	5.6	2.65	5. 65
В	1. 2	4. 2	-	4. 25	V	2.7	5. 7	2.75	5. 75
С	1.3	4. 3	-	4. 35	X	2.8	5.8	2.85	5. 85
D	1.4	4. 4	-	4. 45	Y	2.9	5. 9	2.95	5. 95
Е	1.5	4. 5	1. 55	4. 55	Z	3. 0	6.0	3.05	6.05

4Based on internal standards

 $0\sim9$, $A\sim$ Z repeated G, I, J, O, Q, W are excepted)



"=U series Low Power Voltage Detector"

Absolute Maximum Ratings

Supply Voltage-0.3V to 12V Storage Temperature-50°C to 125°C Operating Temperature-40°C to 85°C

Note: These are stress ratings only. Stresses exceeding the range specified under "Absolute Maximum Ratings" may cause substantial damage to the device. Functional operation of this device at other conditions beyond those listed in the specification is not implied and prolonged exposure to extreme conditions may affect device reliability.

Thermal Information

Symbol	Parameter	Package	Max.	Unit
	Thermal Decistores (Lungtion to	SOT23	500	°C/W
θ ЈА	Thermal Resistance (Junction to Ambient) (Assume no ambient	SOT89	200	°C/W
	airflow, no heat sink)	TO92	200	°C/W
		SOT23	0.20	W
P_D	Power Dissipation	SOT89	0.50	W
		TO92	0.50	W

Note: P_D is measured at Ta= 25 $^{\circ}$ C

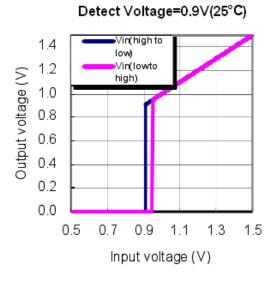
Electrical Characteristics

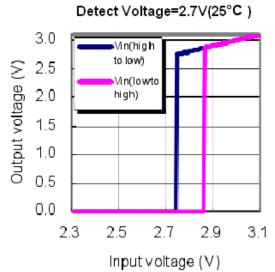
 $V_{DF}=0.8V\sim5.0V$ Ta=25°C

Symbol	Parameter	Те	st Conditions	Min.	Тур.	Max.	Unit
V _{DET}	Detection Voltage	V _{DF} =0.8V~2.2V V _{DF} =2.3V~5.0V		V _{DF} *0.98	V_{DF}	V _{DF} *1.02	V
V _{HYS}	Hysteresis Width		-	0.02 V _{DET}	0.04 V _{DET}	0.08 V _{DET}	V
			Vin=1.5V	-	0.7	2.3	
	Operating Current	Vin=2.0V		-	0.8	2.7	μΑ
I_{DD}		perating Current Vin=3.0V		-	0.9	3.0	
		Vin=4.0V		-	1.0	3.2	
		Vin=5.0V		-	1.1	3.6	
V _{DD}	Operating Voltage	-	-	0.7	-	10	V
I _{OL}	Output Sink Current	2V	V _{OUT} =0.2V	0.5	1	-	mA
$\frac{\Delta V_{\scriptscriptstyle DET}}{V_{\scriptscriptstyle DF}\Delta T_{\scriptscriptstyle a}}$	Temperature Coefficient	-	-25℃ <ta<125℃< td=""><td>-</td><td>± 100</td><td>-</td><td>ppm/°C</td></ta<125℃<>	-	± 100	-	ppm/°C

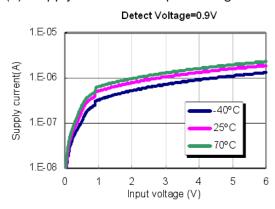
Typical Performance Characteristics

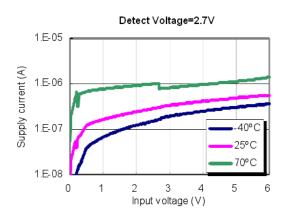
(1) Output Voltage vs Input voltage



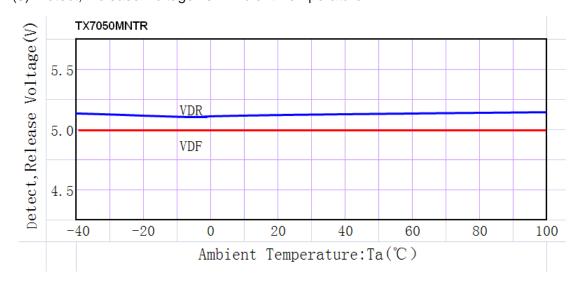


(2) Supply Current vs. Input Voltage





(3) Detect, Release Voltage vs. Ambient Temperature



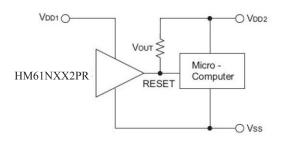


Application Circuits

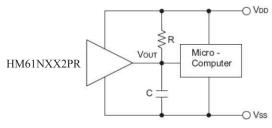
Microcomputer Reset Circuit

Normally a reset circuit is required to protect the microcomputer system from malfunctions due to power line interrupttions. The following examples show how different output configurations perform a reset function in various systems.

NMOS open drain output application for separate power supply

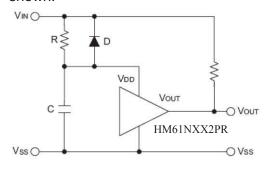


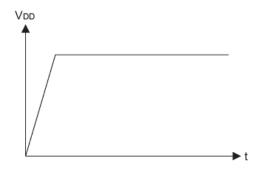
NMOS open drain output application with R-C delay

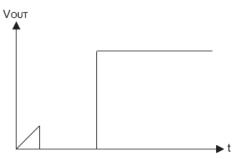


Power-on Reset Circuit

With several external components, the NMOS open drain type of the PTÎFÁ series can be used to perform a power-on reset function as shown:



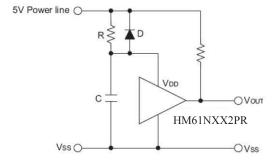




5V Power Line Monitoring Circuit

Generally, a minimum operating voltage of 4.5V is guaranteed in a 5V power line system. The ÁPT Î FÁÁs recommended for use as 5V power line monitoring circuit.

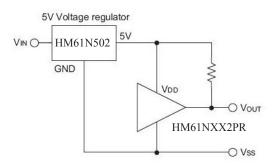
5V power line monitor with power-on reset



With 5V voltage regulator

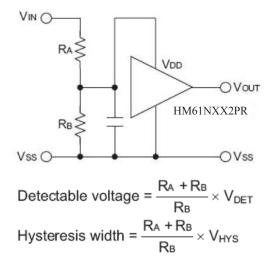
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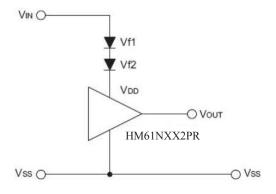


Change of Detectable Voltage

If the required voltage is not found in the standard product selection table, it is possible to change it by using external resistance dividers or diodes. Varying the detectable voltage with a resistance divider



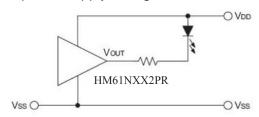
Varying the detectable voltage with a diode



Detectable Voltage = $V_{f1}+V_{f2}+V_{DET}$

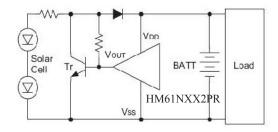
Malfunction Analysis

The following circuit demonstrates the way a circuit analyzes malfunctions by monitoring the variation or spike noise of power supply voltage.



Charge Monitoring Circuit

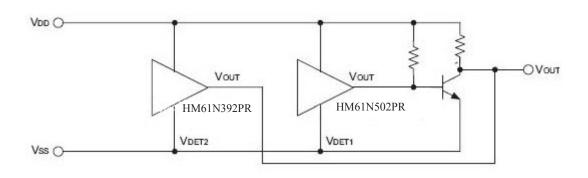
The following circuit shows a charged monitor for protection against battery deterioration by overcharging. When the voltage of the battery is higher than the set detectable voltage, the transistor turns onto bypass the charge current, protecting the battery from overcharging.

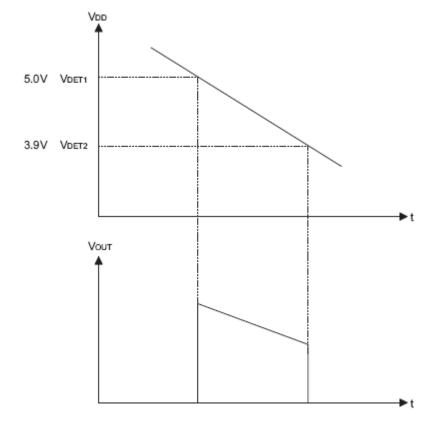


Level Selector

The following diagram illustrates a logic level selector.

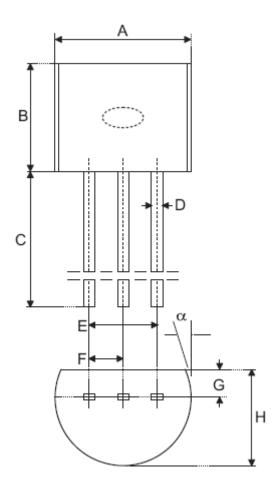
.....=U *series Low Power Voltage Detector







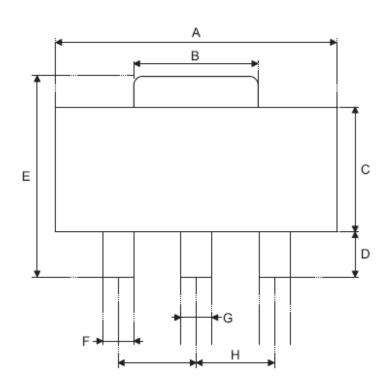
Package Information 3-pin TO92 Outline Dimensions

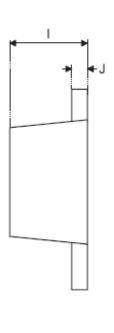


Sumah al	Dimensions in mil					
Symbol	Min.	Nom.	Max.			
Α	170	_	200			
В	170	_	200			
С	500	_	_			
D	11	_	20			
E	90	_	110			
F	45	_	55			
G	45	_	65			
Н	130	_	160			
I	8	_	18			
α	4°	_	6°			



3-pin SOT89 Outline Dimensions

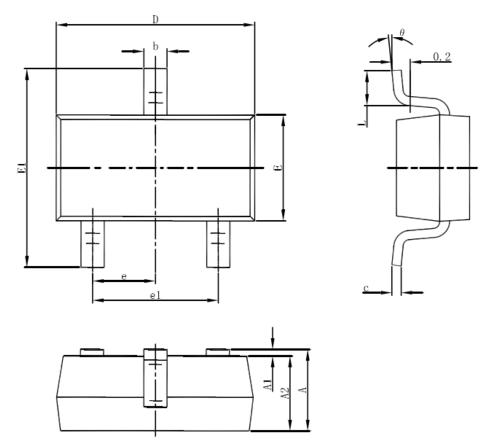




Cumbal	Dimensions in mil				
Symbol	Min.	Nom.	Max.		
Α	173	_	181		
В	59	_	72		
С	90	_	102		
D	35	_	47		
Е	155	_	167		
F	14	_	19		
G	17	_	22		
Н	_	59	_		
I	55	_	63		
J	14	_	17		



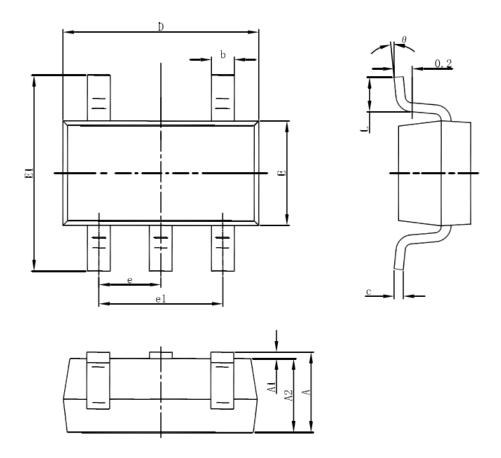
3-pin SOT23-3 Outline Dimensions



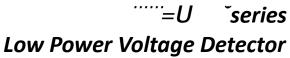
Symbol	Dimensions In	n Millimeters	Dimensions	In Inches
Symbol	Min	Max	Min	Max
Α	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
С	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
Е	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
е	0.950	(BSC)	0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°



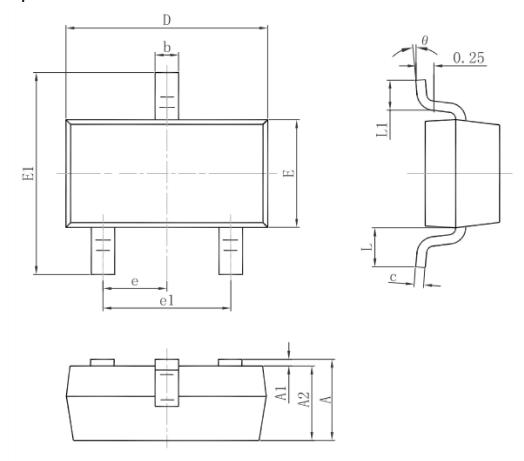
5-pin SOT23-5 Outline Dimensions



Ch - I	Dimensions In	Millimeters	Dimensions	In Inches
Symbol	Min	Max	Min	Max
Α	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
С	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
е	0.950(BSC)	0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°



Package Information 3-pin SOT23 Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
Α	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
С	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
е	0.950 TYP.		0.037 TYP.	
e1	1.800	2.000	0.071	0.079
L	0.550 REF.		0.022 REF.	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°